Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	2	("6198091").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/07 14:54
L3	908568	(thermal adj vaporization) or (cathode adj sputtering) or (solution adj centrifuging) or printing	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/07 14:55
L4	0	((thermal adj vaporization) or (cathode adj sputtering) or (solution adj centrifuging) or printing) and 2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/07 14:55
S 7	222	250/370.07	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/04 12:03
S9	615	measur\$4 same (radiation adj dosage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/03 10:24
S10	284	measur\$4 same (radiation adj dosage) and absorb\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/03 10:26
S11	1	measur\$4 same (radiation adj dosage) and absorb\$5 and (photo adj active)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/03 10:27
S12	30	measur\$4 same (radiation adj dosage) and absorb\$5 and semiconductor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 16:14
S16	180	250/370.07 and measur\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/03 13:45
S17	180	250/370.07 and measur\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/03 14:07

S18	2676	(dosimet\$4).ab.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/03 16:59
S19	302	(dosimet\$4).ab. and (junction or anode or cathode or electrode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 09:20
S22	6	(("4431920") or ("5589699")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/04 09:48
S23	18	(("4431920") or ("5589699") or ("4381450") or ("4999504") or ("5115134") or ("5637876") or ("5767520") or ("5811822") or ("4999504")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/04 10:06
S24	41	(p adj n adj junction) and dosimet\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 16:13
S25	9	250/370.07 and (automatic adj exposure)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 12:03
S26	168	250/370.12	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/04 14:58
S27	13317	film adj electrode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/04 14:58
S28	17952	film adj electrode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 14:58
S29	14872	heterojunction	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 14:58

000	40045	627	HC DCDHS	OD	ON	2005/11/04 14 52
S30	13317	S27 same S28	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 14:59
S31	19	S28 same S29	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 15:00
S32	11	S28 same S29 and radiation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 15:07
S33	117502	pn	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 15:07
S34	65	S28 same pn	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 15:08
S35	0	S28 same pn and (ioniz\$5 adj radiat\$6)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 15:09
S36	39	S27 and (ionizing adj radiation)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 15:49
S37	3	S27 and (ionizing adj radiation) and junction	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 15:18
S38	1	S27 and (ionizing adj radiation) and pn	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 15:18
S39	2	("5022930").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/04 15:34

S40	2	("6398710").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO;	OR	OFF	2005/11/04 15:46
S41	11	S27 and (ionizing adj radiation) and diode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 15:58
S42	15460	(foil near4 substrate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 15:59
S43	3503	(foil near4 substrate) and radiat\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 15:59
S44	125	(foil near4 substrate) and (ionizing adj radiat\$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 16:00
S45	2392	s? and (scintillat\$5).ti.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 16:16
S46	1621	s and (scintillat\$5).ti.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 16:17
S47	2392	s? and (scintillat\$5).ti.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 16:18
S48	2676	(dosimet\$4).ab.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 16:18
S49	44	S48 and (scintillat\$5).ti.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/04 16:18

S50	3708	foil near4 (carrier or substrate) and radiation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/07 06:51
S51	3002	foil near3 (carrier or substrate) and radiation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/07 06:52
S52	42	foil near3 (carrier or substrate) and (dosage near3 radiation)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/07 06:52
S53	2	("5022930").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/07 07:47
S54	136	(organic adj semiconductor) and heterojunction	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/11/07 10:17
S55	122	(organic adj semiconductor) and heterojunction and radiation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/07 10:17
S56	24	(organic adj semiconductor) same heterojunction and radiation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/07 10:44
S57	6	(organic adj semiconductor) same heterojunction and radiation and ((semiconductiong adj conjugate adj polymer) or (low adj molecular adj weight) or monomer or oligomer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/11/07 14:54